

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION

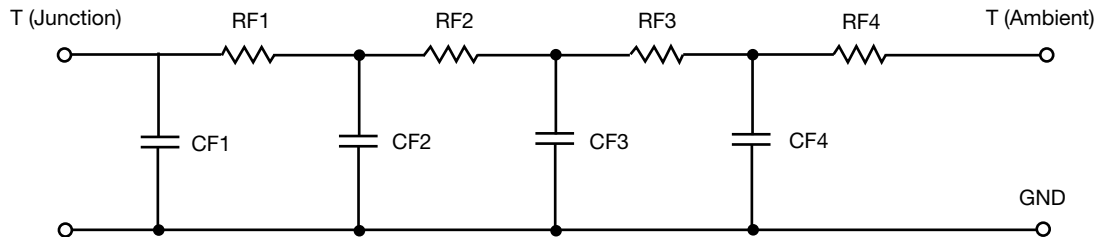


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	32.8548	N/A	7.1460
RT2	26.7348	N/A	24.3475
RT3	9.1333	N/A	7.1975
RT4	55.7145	N/A	6.3132
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	2.3878m	N/A	119.7290m
CT2	34.3007m	N/A	1.3671m
CT3	269.4448u	N/A	9.8963m
CT4	1.2572	N/A	160.7712u

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	8.5805	N/A	2.4817
RF2	31.9082	N/A	7.6578
RF3	28.5328	N/A	27.9409
RF4	55.3027	N/A	6.8118
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	192.0794u	N/A	79.2514u
CF2	1.4945m	N/A	183.3458u
CF3	20.0489m	N/A	1.1674m
CF4	1.2080	N/A	98.2840m

**Note**

N/A indicates not applicable

